

- Qualified for Automotive Applications
- 150-mA Low-Dropout Regulator
- Output Voltage: 5 V, 3.8 V, 3.3 V, 3 V, 2.8 V, 2.7 V, 2.5 V, 1.8 V, 1.6 V and Variable
- Dropout Voltage, Typically 300 mV at 150 mA
- Thermal Protection
- Overcurrent Limitation
- Less Than 2- μ A Quiescent Current in Shutdown Mode
- -40°C to 125°C Operating Junction Temperature Range
- 5-Pin SOT-23 (DBV) Package



description

The TPS763xx family of low-dropout (LDO) voltage regulators offers the benefits of low-dropout voltage, low-power operation, and miniaturized packaging. These regulators feature low dropout voltages and quiescent currents compared to conventional LDO regulators. Offered in a 5-terminal, small outline integrated-circuit SOT-23 package, the TPS763xx series devices are ideal for cost-sensitive designs and for applications where board space is at a premium.

A combination of new circuit design and process innovation has enabled the usual pnp pass transistor to be replaced by a PMOS pass element. Because the PMOS pass element behaves as a low-value resistor, the dropout voltage is low—typically 300 mV at 150 mA of load current (TPS76333)—and is directly proportional to the load current. Since the PMOS pass element is a voltage-driven device, the quiescent current is low (140 μ A maximum) and is stable over the entire range of output load current (0 mA to 150 mA). Intended for use in portable systems such as laptops and cellular phones, the low-dropout voltage feature and low-power operation result in a significant increase in system battery operating life.

The TPS763xx also features a logic-enabled sleep mode to shut down the regulator, reducing quiescent current to 1 μ A maximum at $T_J = 25^\circ\text{C}$. The TPS763xx is offered in 1.6-V, 1.8-V, 2.5-V, 2.7-V, 2.8-V, 3-V, 3.3-V, 3.8-V, and 5-V fixed-voltage versions and in a variable version (programmable over the range of 1.5 V to 6.5 V).

AVAILABLE OPTIONS[†]

T_J	VOLTAGE	PACKAGE [‡]	PART NUMBER	SYMBOL
-40°C to 125°C	Variable	SOT-23 (DBV)	TPS76301QDBVRQ1	BAN
	1.6 V		TPS76316QDBVRQ1	BAD
	1.8 V		TPS76318QDBVRQ1	BAP
	2.5 V		TPS76325QDBVRQ1	BAQ
	2.7 V		TPS76327QDBVRQ1 [§]	
	2.8 V		TPS76328QDBVRQ1 [§]	
	3 V		TPS76330QDBVRQ1	BAT
	3.3 V		TPS76333QDBVRQ1	BAU
	3.8 V		TPS76338QDBVRQ1 [§]	
	5.0 V		TPS76350QDBVRQ1	BAW

[†] For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at <http://www.ti.com>.

[‡] Package drawings, thermal data, and symbolization are available at <http://www.ti.com/packaging>.

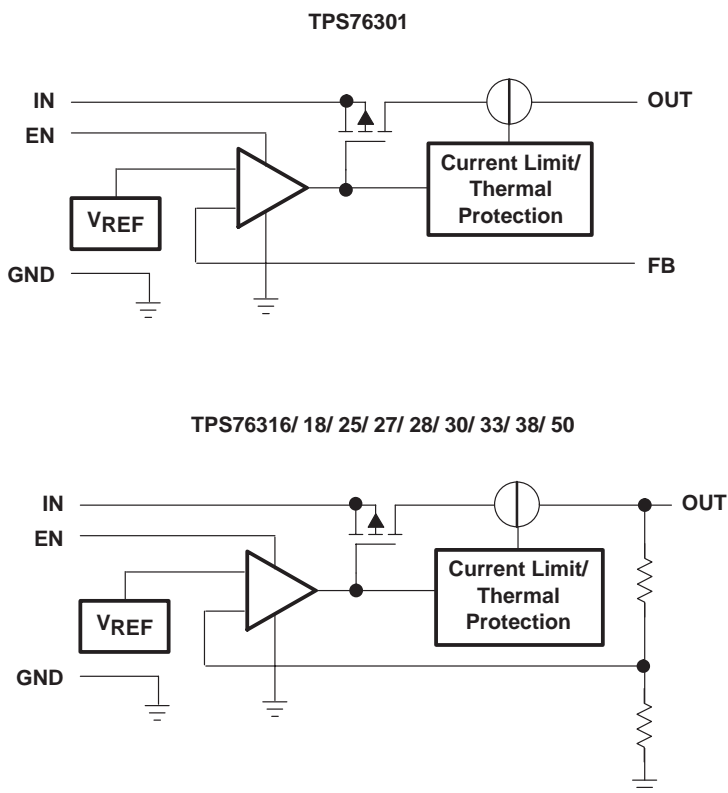
[§] Product Preview. Contact Texas Instruments for availability.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

All trademarks are the property of their respective owners.

functional block diagram



Terminal Functions

TERMINAL NAME	DESCRIPTION
GND	Ground
EN	Enable input
FB	Feedback voltage (TPS76301 only)
IN	Input supply voltage
NC	No connection (fixed-voltage option only)
OUT	Regulated output voltage

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)⁽¹⁾

Input voltage range ⁽²⁾	–0.3 V to 10 V
Voltage range at EN	–0.3 V to $V_I + 0.3$ V
Voltage on OUT, FB	7 V
Peak output current	Internally limited
ESD rating, HBM	2 kV
Continuous total power dissipation	See Dissipation Rating Tables
Operating junction temperature range, T_J	–40°C to 150°C
Storage temperature range, T_{Stg}	–65°C to 150°C

(1) Stresses beyond those listed under *absolute maximum ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *recommended operating conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) All voltage values are with respect to network ground terminal.

DISSIPATION RATING TABLE

BOARD	PACKAGE	$R_{\theta JC}$	$R_{\theta JA}$	DERATING FACTOR ABOVE $T_A = 25^\circ\text{C}$	$T_A \leq 25^\circ\text{C}$ POWER RATING	$T_A = 70^\circ\text{C}$ POWER RATING	$T_A = 85^\circ\text{C}$ POWER RATING
Low K ⁽¹⁾	DBV	65.8°C/W	259°C/W	3.9 mW/°C	386 mW	212 mW	154 mW
High K ⁽²⁾	DBV	65.8°C/W	180°C/W	5.6 mW/°C	555 mW	305 mW	222 mW

(1) The JEDEC Low K (1s) board design used to derive this data was a 3 inch x 3 inch, two layer board with 2 ounce copper traces on top of the board.

(2) The JEDEC High K (2s2p) board design used to derive this data was a 3 inch x 3 inch, multilayer board with 1 ounce internal power and ground planes and 2 ounce copper traces on top and bottom of the board.

recommended operating conditions

	MIN	NOM	MAX	UNIT
Input voltage, V_I ⁽¹⁾	2.7		10	V
Continuous output current, I_O	0		150	mA
Operating junction temperature, T_J	–40		125	°C

(1) To calculate the minimum input voltage for your maximum output current, use the following equation:

$$V_{I(\min)} = V_{O(\max)} + V_{DO(\max \text{ load})}$$

**TPS76301-Q1, TPS76316-Q1, TPS76318-Q1, TPS76325-Q1, TPS76327-Q1
TPS76328-Q1, TPS76330-Q1, TPS76333-Q1, TPS76338-Q1, TPS76350-Q1
LOW-POWER 150-mA LOW-DROPOUT LINEAR REGULATORS**



SGLS247A – JUNE 2004 – REVISED JUNE 2008

**electrical characteristics over recommended operating free-air temperature range,
 $V_I = V_O(\text{typ}) + 1 \text{ V}$, $I_O = 1 \text{ mA}$, $EN = IN$, $C_O = 4.7 \mu\text{F}$ (unless otherwise noted)**

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT	
V_O	Output voltage	TPS76301	$3.25 \text{ V} > V_I \geq 2.7 \text{ V}$, $2.5 \text{ V} \geq V_O \geq 1.5 \text{ V}$,	$I_O = 1 \text{ mA}$ to 75 mA , $T_J = 25^\circ\text{C}$	$0.98 V_O$	V_O	$1.02 V_O$	V
			$3.25 \text{ V} > V_I \geq 2.7 \text{ V}$, $2.5 \text{ V} \geq V_O \geq 1.5 \text{ V}$	$I_O = 1 \text{ mA}$ to 75 mA ,	$0.97 V_O$	V_O	$1.03 V_O$	
			$V_I \geq 3.25 \text{ V}$, $5 \text{ V} \geq V_O \geq 1.5 \text{ V}$	$I_O = 1 \text{ mA}$ to 100 mA , $T_J = 25^\circ\text{C}$	$0.98 V_O$	V_O	$1.02 V_O$	
			$V_I \geq 3.25 \text{ V}$, $5 \text{ V} \geq V_O \geq 1.5 \text{ V}$	$I_O = 1 \text{ mA}$ to 100 mA ,	$0.97 V_O$	V_O	$1.03 V_O$	
			$V_I \geq 3.25 \text{ V}$, $5 \text{ V} \geq V_O \geq 1.5 \text{ V}$	$I_O = 1 \text{ mA}$ to 150 mA , $T_J = 25^\circ\text{C}$	$0.975 V_O$	V_O	$1.025 V_O$	
			$V_I \geq 3.25 \text{ V}$, $5 \text{ V} \geq V_O \geq 1.5 \text{ V}$	$I_O = 1 \text{ mA}$ to 150 mA ,	$0.9625 V_O$	V_O	$1.0375 V_O$	
		TPS76316	$V_I = 2.7 \text{ V}$,	$1 \text{ mA} < I_O < 75 \text{ mA}$, $T_J = 25^\circ\text{C}$	1.568	1.6	1.632	V
			$V_I = 2.7 \text{ V}$,	$1 \text{ mA} < I_O < 75 \text{ mA}$	1.552	1.6	1.648	
			$V_I = 3.25 \text{ V}$,	$1 \text{ mA} < I_O < 100 \text{ mA}$, $T_J = 25^\circ\text{C}$	1.568	1.6	1.632	
			$V_I = 3.25 \text{ V}$,	$1 \text{ mA} < I_O < 100 \text{ mA}$	1.552	1.6	1.648	
			$V_I = 3.25 \text{ V}$,	$1 \text{ mA} < I_O < 150 \text{ mA}$, $T_J = 25^\circ\text{C}$	1.56	1.6	1.640	
			$V_I = 3.25 \text{ V}$,	$1 \text{ mA} < I_O < 150 \text{ mA}$	1.536	1.6	1.664	
		TPS76318	$V_I = 2.7 \text{ V}$,	$1 \text{ mA} < I_O < 75 \text{ mA}$, $T_J = 25^\circ\text{C}$	1.764	1.8	1.836	V
			$V_I = 2.7 \text{ V}$,	$1 \text{ mA} < I_O < 75 \text{ mA}$	1.746	1.8	1.854	
			$V_I = 3.25 \text{ V}$,	$1 \text{ mA} < I_O < 100 \text{ mA}$, $T_J = 25^\circ\text{C}$	1.764	1.8	1.836	
			$V_I = 3.25 \text{ V}$,	$1 \text{ mA} < I_O < 100 \text{ mA}$	1.746	1.8	1.854	
			$V_I = 3.25 \text{ V}$,	$1 \text{ mA} < I_O < 150 \text{ mA}$, $T_J = 25^\circ\text{C}$	1.755	1.8	1.845	
			$V_I = 3.25 \text{ V}$,	$1 \text{ mA} < I_O < 150 \text{ mA}$	1.733	1.8	1.867	
		TPS76325	$I_O = 1 \text{ mA}$ to 100 mA , $T_J = 25^\circ\text{C}$		2.45	2.5	2.55	V
			$I_O = 1 \text{ mA}$ to 100 mA		2.425	2.5	2.575	
			$I_O = 1 \text{ mA}$ to 150 mA , $T_J = 25^\circ\text{C}$		2.438	2.5	2.562	
			$I_O = 1 \text{ mA}$ to 150 mA		2.407	2.5	2.593	
		TPS76327	$I_O = 1 \text{ mA}$ to 100 mA , $T_J = 25^\circ\text{C}$		2.646	2.7	2.754	V
			$I_O = 1 \text{ mA}$ to 100 mA		2.619	2.7	2.781	
			$I_O = 1 \text{ mA}$ to 150 mA , $T_J = 25^\circ\text{C}$		2.632	2.7	2.767	
			$I_O = 1 \text{ mA}$ to 150 mA		2.599	2.7	2.801	
		TPS76328	$I_O = 1 \text{ mA}$ to 100 mA , $T_J = 25^\circ\text{C}$		2.744	2.8	2.856	V
			$I_O = 1 \text{ mA}$ to 100 mA		2.716	2.8	2.884	
			$I_O = 1 \text{ mA}$ to 150 mA , $T_J = 25^\circ\text{C}$		2.73	2.8	2.87	
			$I_O = 1 \text{ mA}$ to 150 mA		2.695	2.8	2.905	
TPS76330	$I_O = 1 \text{ mA}$ to 100 mA , $T_J = 25^\circ\text{C}$		2.94	3	3.06	V		
	$I_O = 1 \text{ mA}$ to 100 mA		2.91	3	3.09			
	$I_O = 1 \text{ mA}$ to 150 mA , $T_J = 25^\circ\text{C}$		2.925	3	3.075			
	$I_O = 1 \text{ mA}$ to 150 mA		2.888	3	3.112			

electrical characteristics over recommended operating free-air temperature range,
 $V_I = V_{O(\text{typ})} + 1 \text{ V}$, $I_O = 1 \text{ mA}$, $EN = IN$, $C_O = 4.7 \mu\text{F}$ (unless otherwise noted) (continued)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT	
V_O	Output voltage	TPS76333	$I_O = 1 \text{ mA to } 100 \text{ mA}$, $T_J = 25^\circ\text{C}$		3.234	3.3	3.366
			$I_O = 1 \text{ mA to } 100 \text{ mA}$		3.201	3.3	3.399
			$I_O = 1 \text{ mA to } 150 \text{ mA}$, $T_J = 25^\circ\text{C}$		3.218	3.3	3.382
			$I_O = 1 \text{ mA to } 150 \text{ mA}$		3.177	3.3	3.423
		TPS76338	$I_O = 1 \text{ mA to } 100 \text{ mA}$, $T_J = 25^\circ\text{C}$		3.724	3.8	3.876
			$I_O = 1 \text{ mA to } 100 \text{ mA}$		3.705	3.8	3.895
			$I_O = 1 \text{ mA to } 150 \text{ mA}$, $T_J = 25^\circ\text{C}$		3.686	3.8	3.914
			$I_O = 1 \text{ mA to } 150 \text{ mA}$		3.667	3.8	3.933
		TPS76350	$I_O = 1 \text{ mA to } 100 \text{ mA}$, $T_J = 25^\circ\text{C}$		4.875	5	5.125
			$I_O = 1 \text{ mA to } 100 \text{ mA}$		4.825	5	5.175
			$I_O = 1 \text{ mA to } 150 \text{ mA}$, $T_J = 25^\circ\text{C}$		4.750	5	5.15
			$I_O = 1 \text{ mA to } 150 \text{ mA}$		4.80	5	5.20
$I_{(Q)}$	Quiescent current (GND terminal current)	$I_O = 0 \text{ to } 150 \text{ mA}$, $T_J = 25^\circ\text{C}$ (1)		85	100	μA	
		$I_O = 0 \text{ to } 150 \text{ mA}$ see (2)			140		
	Standby current	$EN < 0.5 \text{ V}$, $T_J = 25^\circ\text{C}$		0.5	1	μA	
		$EN < 0.5 \text{ V}$			2		
V_n	Output noise voltage	BW = 300 Hz to 50 kHz, $C_O = 10 \mu\text{F}$ (2) $T_J = 25^\circ\text{C}$,		140		μV	
PSRR	Ripple rejection	$f = 1 \text{ kHz}$, $C_O = 10 \mu\text{F}$, $T_J = 25^\circ\text{C}$ (2)		60		dB	
	Current limit	$T_J = 25^\circ\text{C}$, see (3)		0.5	0.8	1.5	A
	Output voltage line regulation ($\Delta V_O/V_O$), (see (3))	$V_O + 1 \text{ V} < V_I \leq 10 \text{ V}$, $V_I \geq 3.5 \text{ V}$, $T_J = 25^\circ\text{C}$		0.04	0.07	%V	
		$V_O + 1 \text{ V} < V_I \leq 10 \text{ V}$, $V_I \geq 3.5 \text{ V}$			0.1		
V_{IH}	EN high level input	See (2)		1.4	2	V	
V_{IL}	EN low level input	See (2)		0.5	1.2		
I_I	EN input current	$EN = 0 \text{ V}$		-0.01	-0.5	μA	
		$EN = IN$		-0.01	-0.5		

(1) Minimum I_N operating voltage is 2.7 V or $V_{O(\text{typ})} + 1 \text{ V}$, whichever is greater.

(2) Test condition includes: output voltage $V_O = 0 \text{ V}$ (for variable device FB is shorted to V_O) and pulse duration = 10 ms.

(3) If $V_O < 2.5 \text{ V}$ and $V_{I\text{max}} = 10 \text{ V}$, $V_{I\text{min}} = 3.5 \text{ V}$:

$$\text{Line Reg. (mV)} = (\%/V) \times \frac{V_O(V_{I\text{max}} - 3.5 \text{ V})}{100} \times 1000$$

If $V_O > 2.5 \text{ V}$ and $V_{I\text{max}} = 10 \text{ V}$, $V_{I\text{min}} = V_O + 1 \text{ V}$:

$$\text{Line Reg. (mV)} = (\%/V) \times \frac{V_O(V_{I\text{max}} - (V_O + 1))}{100} \times 1000$$

TPS76301-Q1, TPS76316-Q1, TPS76318-Q1, TPS76325-Q1, TPS76327-Q1
 TPS76328-Q1, TPS76330-Q1, TPS76333-Q1, TPS76338-Q1, TPS76350-Q1
 LOW-POWER 150-mA LOW-DROPOUT LINEAR REGULATORS

SGLS247A – JUNE 2004 – REVISED JUNE 2008

electrical characteristics over recommended operating free-air temperature range,
 $V_I = V_{O(typ)} + 1\text{ V}$, $I_O = 1\text{ mA}$, $EN = IN$, $C_O = 4.7\text{ }\mu\text{F}$ (unless otherwise noted) (continued)

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
V _{DO}	Dropout voltage	TPS76325	I _O = 0 mA, T _J = 25°C		0.2		mV
			I _O = 1 mA, T _J = 25°C		3		
			I _O = 50 mA, T _J = 25°C		120	150	
			I _O = 50 mA			200	
			I _O = 75 mA, T _J = 25°C		180	225	
			I _O = 75 mA			300	
			I _O = 100 mA, T _J = 25°C		240	300	
			I _O = 100 mA			400	
			I _O = 150 mA, T _J = 25°C		360	450	
		I _O = 150 mA			600		
		TPS76333	I _O = 0 mA, T _J = 25°C		0.2		mV
			I _O = 1 mA, T _J = 25°C		3		
			I _O = 50 mA, T _J = 25°C		100	125	
			I _O = 50 mA			166	
			I _O = 75 mA, T _J = 25°C		150	188	
			I _O = 75 mA			250	
			I _O = 100 mA, T _J = 25°C		200	250	
			I _O = 100 mA			333	
			I _O = 150 mA, T _J = 25°C		300	375	
		I _O = 150 mA			500		
		TPS76350	I _O = 0 mA, T _J = 25°C		0.2		mV
			I _O = 1 mA, T _J = 25°C		2		
			I _O = 50 mA, T _J = 25°C		60	75	
			I _O = 50 mA			100	
			I _O = 75 mA, T _J = 25°C		90	113	
			I _O = 75 mA			150	
			I _O = 100 mA, T _J = 25°C		120	150	
I _O = 100 mA				200			
I _O = 150 mA, T _J = 25°C			180	225			
I _O = 150 mA			300				

TYPICAL CHARACTERISTICS

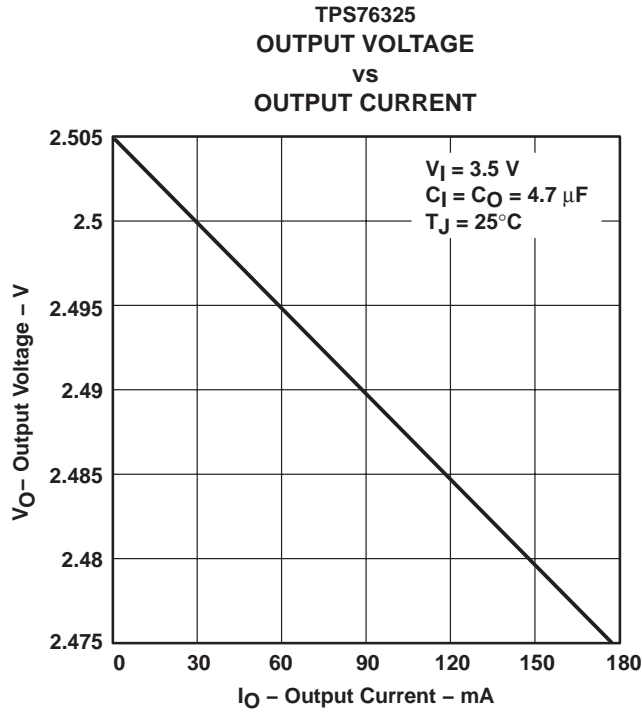


Figure 1

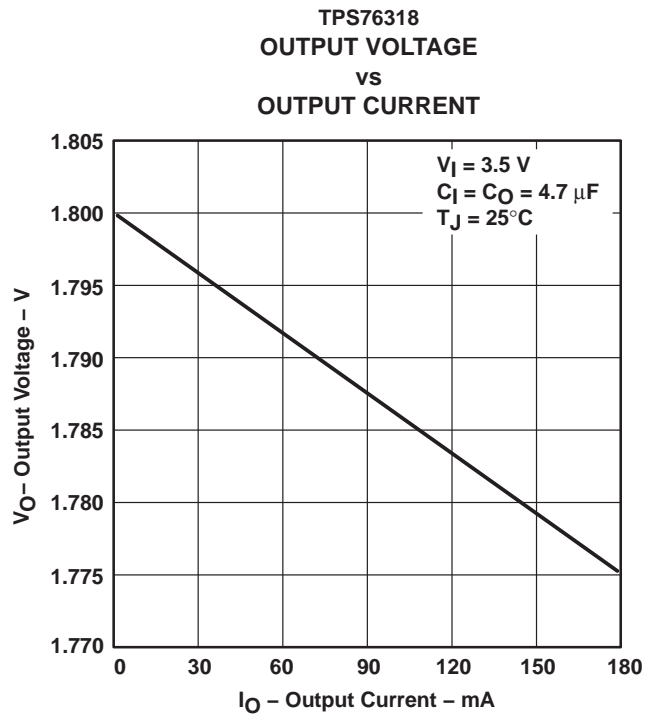


Figure 2

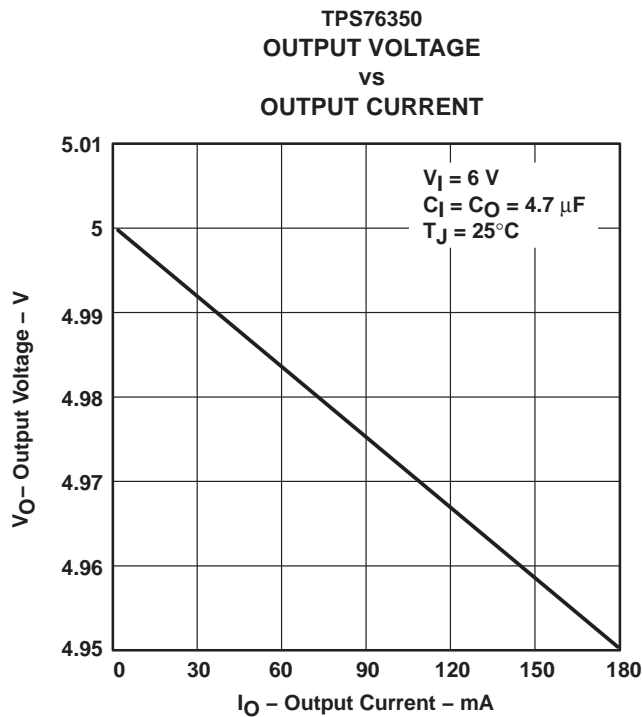


Figure 3

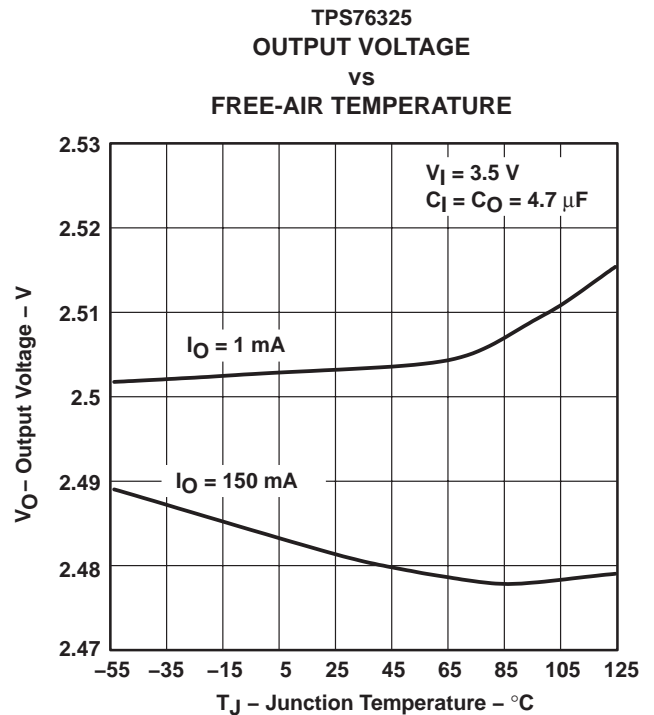
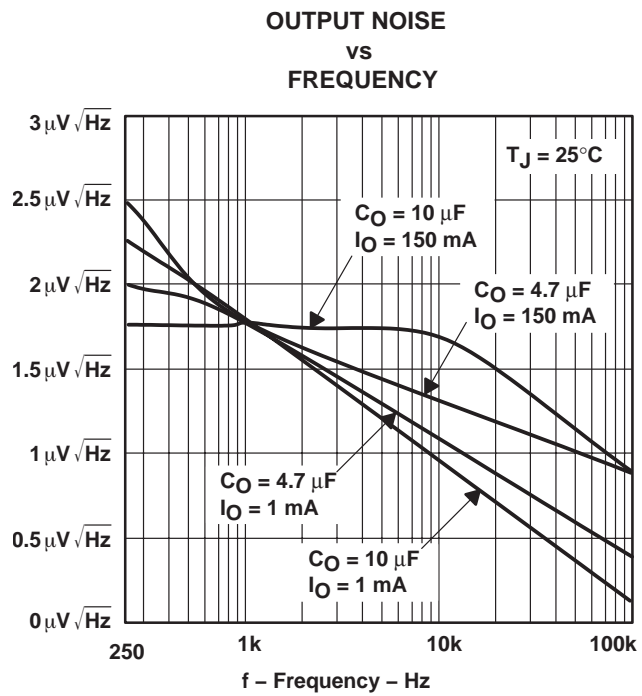
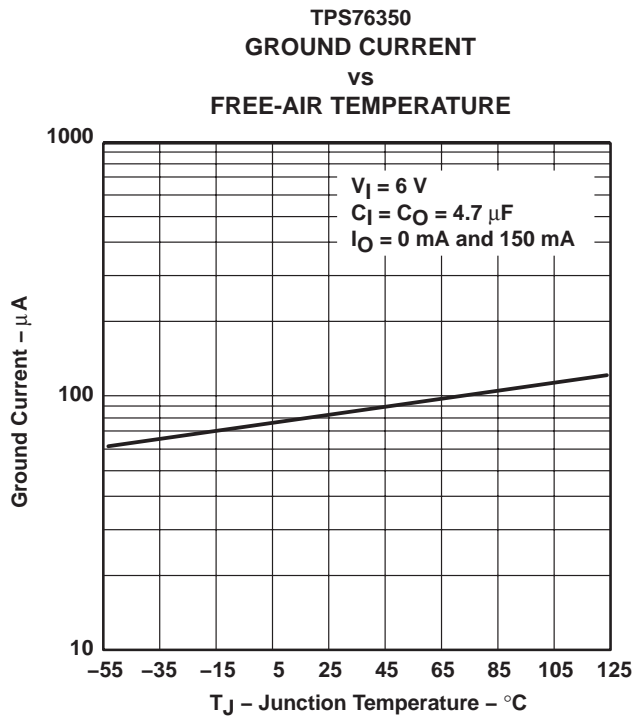
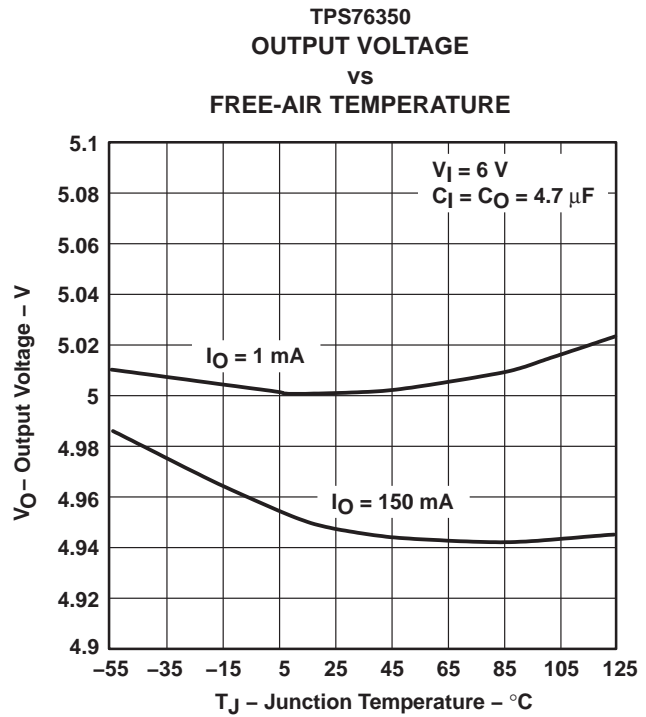
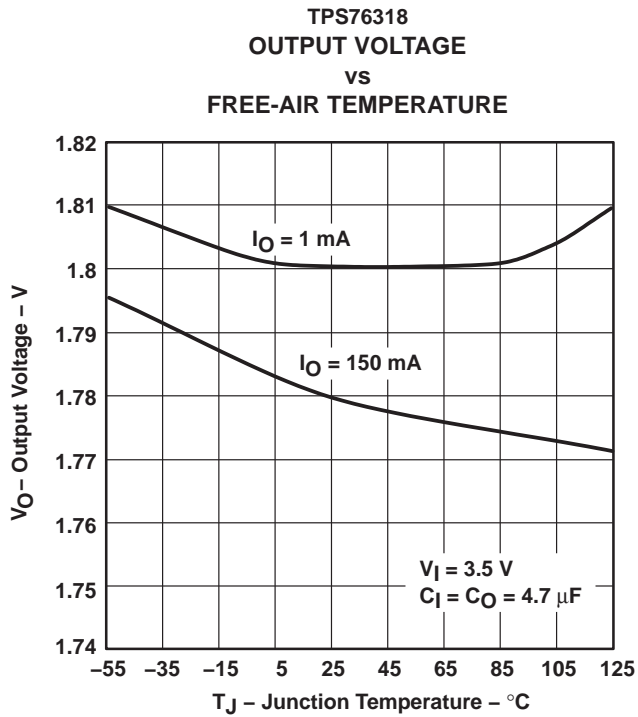


Figure 4

TYPICAL CHARACTERISTICS



TYPICAL CHARACTERISTICS

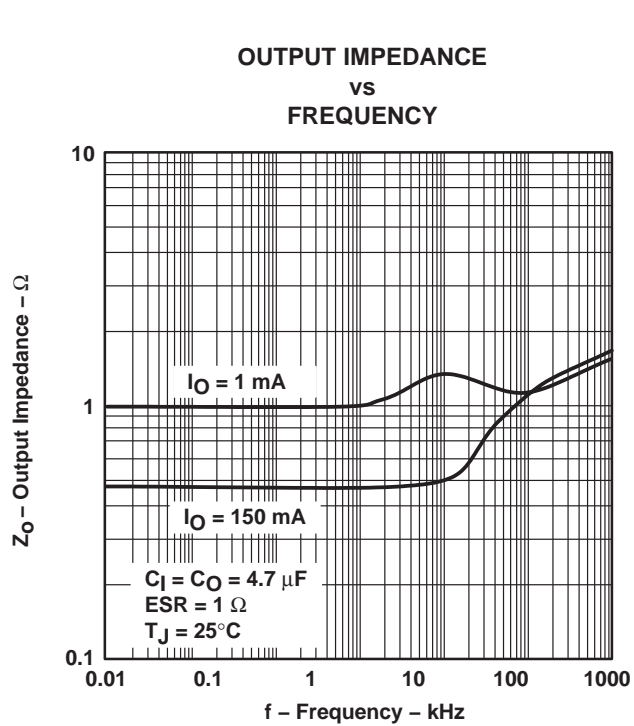


Figure 9

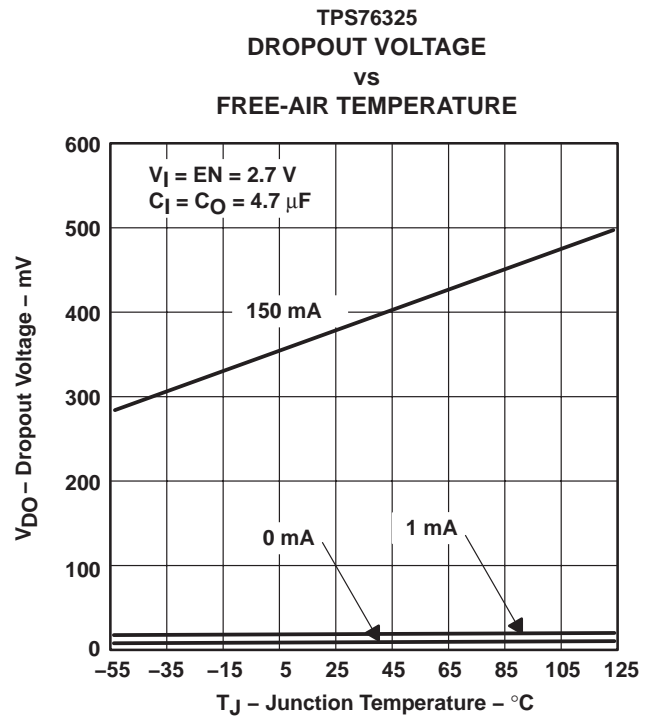


Figure 10

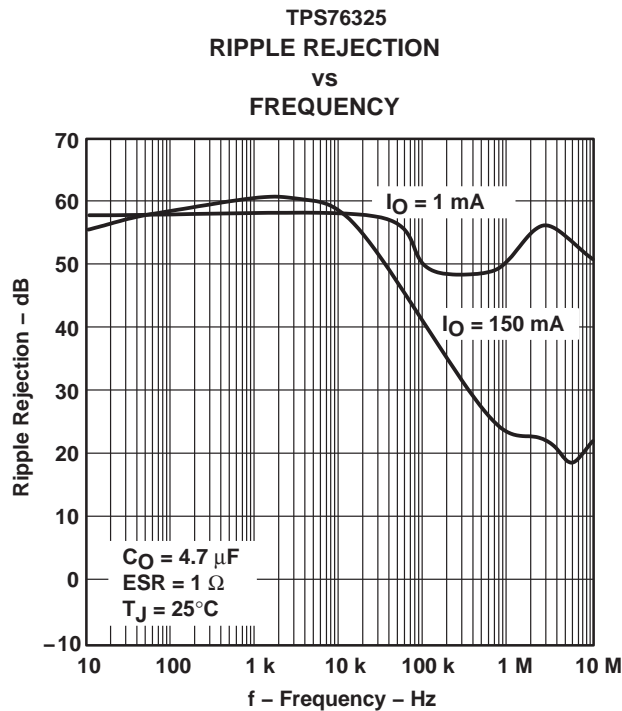


Figure 11

TYPICAL CHARACTERISTICS

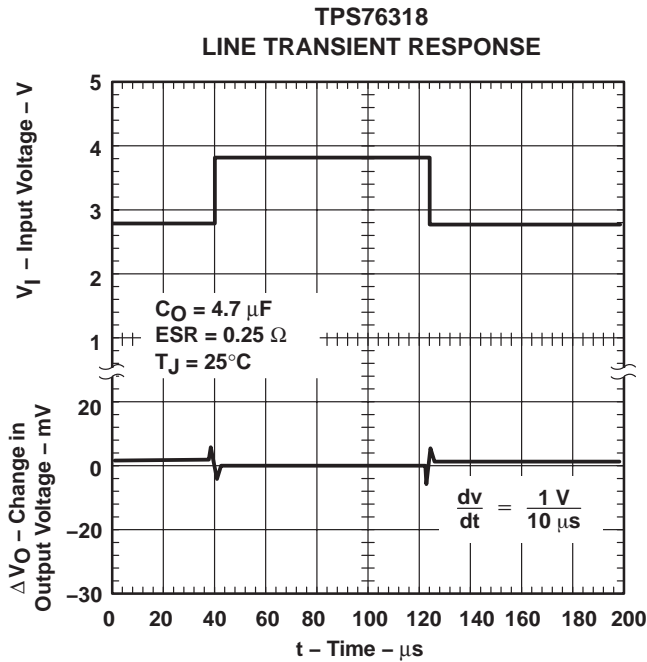


Figure 12

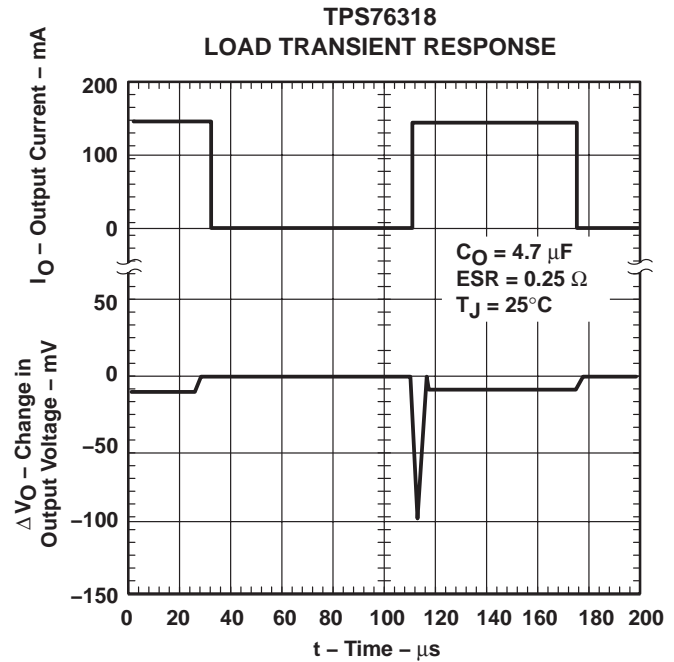


Figure 13

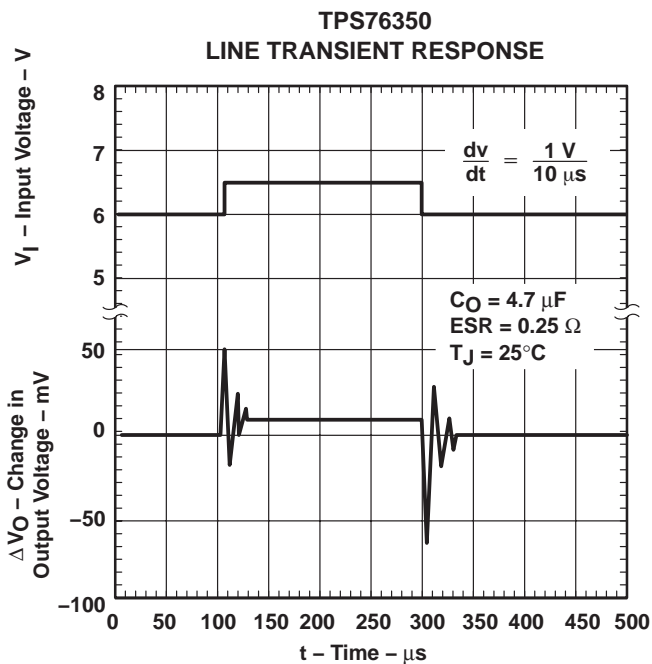


Figure 14

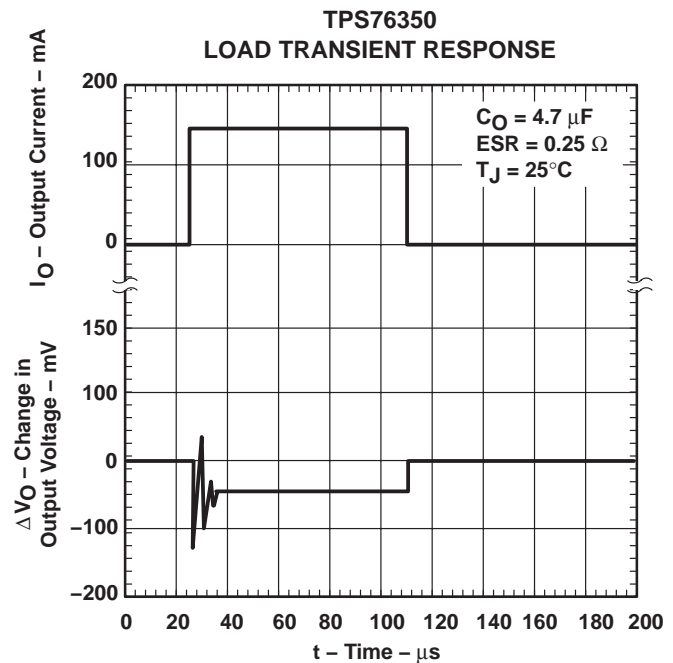


Figure 15

TYPICAL CHARACTERISTICS

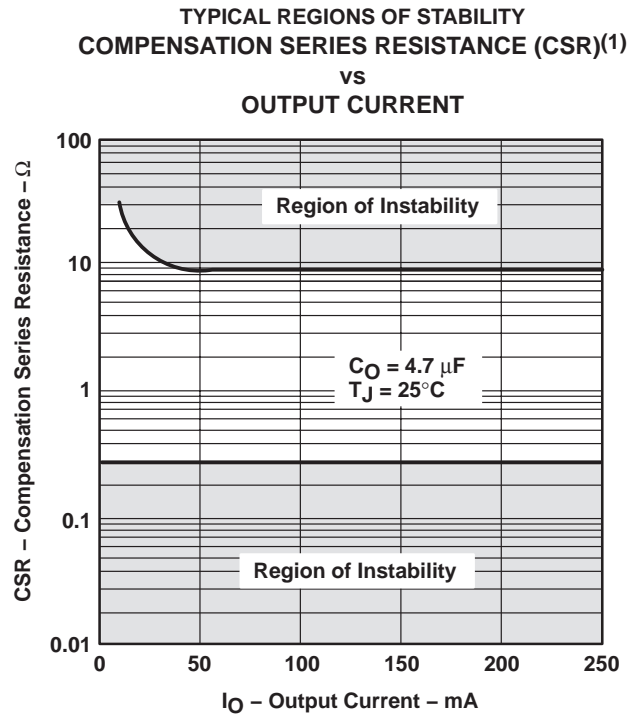


Figure 16

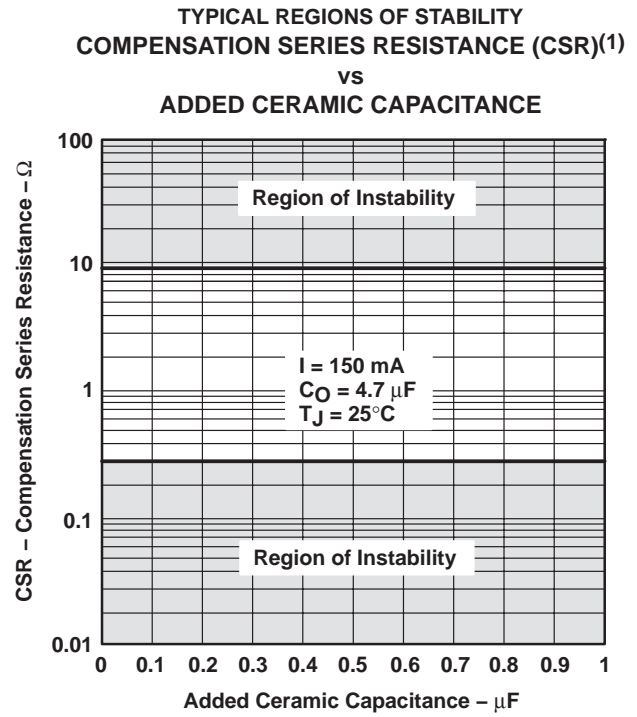


Figure 17

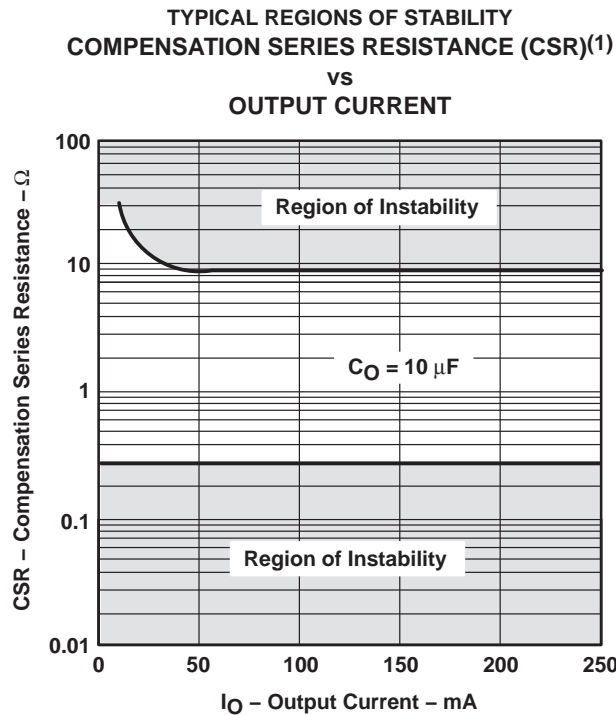


Figure 18

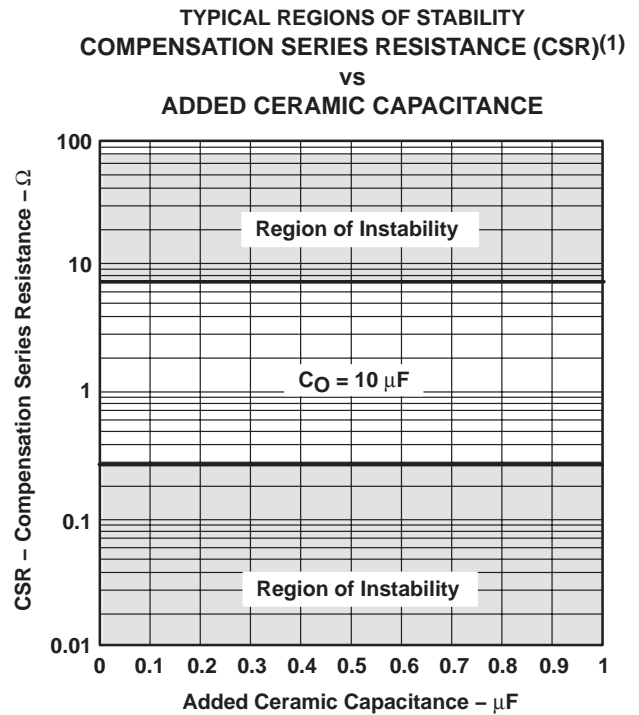


Figure 19

(1) CSR refers to the total series resistance, including the ESR of the capacitor, any series resistance added externally, and PWB trace resistance to C_O .

APPLICATION INFORMATION

The TPS763xx low-dropout (LDO) regulators are new families of regulators which have been optimized for use in battery-operated equipment and feature low dropout voltages, low quiescent current (140 μ A), and an enable input to reduce supply currents to less than 2 μ A when the regulator is turned off.

device operation

The TPS763xx uses a PMOS pass element to dramatically reduce both dropout voltage and supply current over more conventional PNP pass element LDO designs. The PMOS pass element is a voltage-controlled device that, unlike a PNP transistor, does not require increased drive current as output current increases. Supply current in the TPS763xx is essentially constant from no-load to maximum load.

Current limiting and thermal protection prevent damage by excessive output current and/or power dissipation. The device switches into a constant-current mode at approximately 1 A; further load reduces the output voltage instead of increasing the output current. The thermal protection shuts the regulator off if the junction temperature rises above 165°C. Recovery is automatic when the junction temperature drops approximately 25°C below the high temperature trip point. The PMOS pass element includes a back diode that safely conducts reverse current when the input voltage level drops below the output voltage level.

A logic low on the enable input, EN shuts off the output and reduces the supply current to less than 2 μ A. EN should be tied high in applications where the shutdown feature is not used.

A typical application circuit is shown in Figure 20.



(1) TPS76316, TPS76318, TPS76325, TPS76327, TPS76328,
 TPS76330, TPS76333, TPS76338, TPS76350 (fixed-voltage options).

Figure 20. Typical Application Circuit

APPLICATION INFORMATION

external capacitor requirements

Although not required, a 0.047 μF or larger ceramic bypass input capacitor, connected between IN and GND and located close to the TPS763xx, is recommended to improve transient response and noise rejection. A higher-value electrolytic input capacitor may be necessary if large, fast-rise-time load transients are anticipated and the device is located several inches from the power source.

Like all low dropout regulators, the TPS763xx requires an output capacitor connected between OUT and GND to stabilize the internal loop control. The minimum recommended capacitance value is 4.7 μF and the ESR (equivalent series resistance) must be between 0.3 Ω and 10 Ω . Capacitor values of 4.7 μF or larger are acceptable, provided the ESR is less than 10 Ω . Solid tantalum electrolytic, aluminum electrolytic, and multilayer ceramic capacitors are all suitable, provided they meet the requirements described above. Most of the commercially available 4.7- μF surface-mount solid tantalum capacitors, including devices from Sprague, Kemet, and Nichico, meet the ESR requirements stated above.

CAPACITOR SELECTION

PART NO.	MFR.	VALUE	MAX ESR ⁽¹⁾	SIZE (H L W) [†]
T494B475K016AS	KEMET	4.7 μF	1.5 Ω	1.9 × 3.5 × 2.8
195D106x0016x2T	SPRAGUE	10 μF	1.5 Ω	1.3 × 7.0 × 2.7
695D106x003562T	SPRAGUE	10 μF	1.3 Ω	2.5 × 7.6 × 2.5
TPSC475K035R0600	AVX	4.7 μF	0.6 Ω	2.6 × 6.0 × 3.2

⁽¹⁾ Size is in mm. ESR is maximum resistance in ohms at 100 kHz and $T_A = 25^\circ\text{C}$. Listings are sorted by height.

output voltage programming

The output voltage of the TPS76301 adjustable regulator is programmed using an external resistor divider as shown in Figure 21. The output voltage is calculated using:

$$V_O = 0.995 \times V_{\text{ref}} \times \left(1 + \frac{R1}{R2} \right) \quad (1)$$

Where:

$V_{\text{ref}} = 1.192 \text{ V typ}$ (the internal reference voltage)

0.995 is a constant used to center the load regulator (1%)

Resistors R1 and R2 should be chosen for approximately 7- μA divider current. Lower value resistors can be used, but offer no inherent advantage and waste more power. Higher values should be avoided as leakage currents at FB increase the output voltage error. The recommended design procedure is to choose $R2 = 169 \text{ k}\Omega$ to set the divider current at 7 μA and then calculate R1 using:

$$R1 = \left(\frac{V_O}{0.995 \times V_{\text{ref}}} - 1 \right) \times R2 \quad (2)$$

APPLICATION INFORMATION

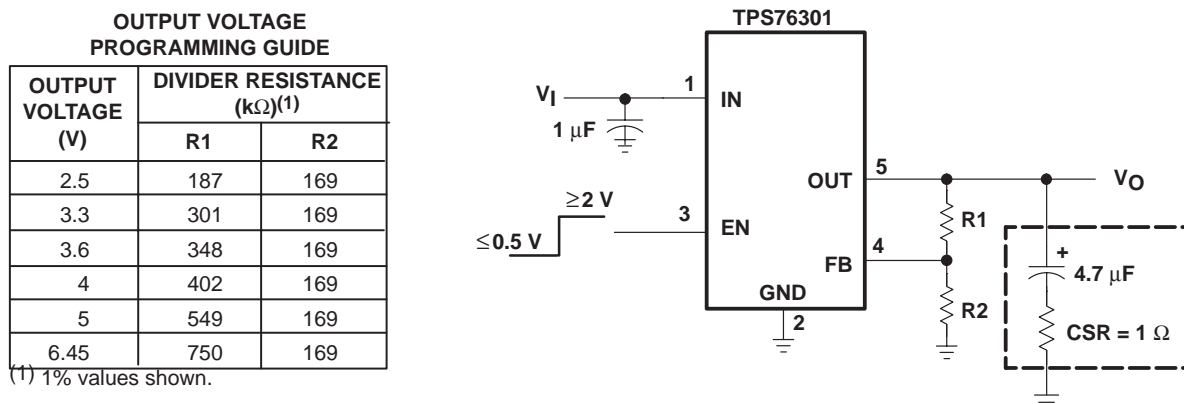


Figure 21. TPS76301 Adjustable LDO Regulator Programming

power dissipation and junction temperature

Specified regulator operation is assured to a junction temperature of 125°C; the maximum junction temperature allowable to avoid damaging the device is 150°C. This restriction limits the power dissipation the regulator can handle in any given application. To ensure the junction temperature is within acceptable limits, calculate the maximum allowable dissipation, $P_{D(max)}$ and the actual dissipation, P_D , which must be less than or equal to $P_{D(max)}$.

The maximum-power-dissipation limit is determined using the following equation:

$$P_{D(max)} = \frac{T_{Jmax} - T_A}{R_{\theta JA}}$$

Where:

T_{Jmax} is the maximum allowable junction temperature

$R_{\theta JA}$ is the thermal resistance junction-to-ambient for the package, see the dissipation rating table.

T_A is the ambient temperature.

The regulator dissipation is calculated using:

$$P_D = (V_I - V_O) \times I_O$$

Power dissipation resulting from quiescent current is negligible.

regulator protection

The TPS763xx pass element has a built-in back diode that safely conducts reverse currents when the input voltage drops below the output voltage (e.g., during power down). Current is conducted from the output to the input and is not internally limited. If extended reverse voltage is anticipated, external limiting might be appropriate.

The TPS763xx also features internal current limiting and thermal protection. During normal operation, the TPS763xx limits output current to approximately 800 mA. When current limiting engages, the output voltage scales back linearly until the overcurrent condition ends. While current limiting is designed to prevent gross device failure, care should be taken not to exceed the power dissipation ratings of the package. If the temperature of the device exceeds 165°C, thermal-protection circuitry shuts it down. Once the device has cooled down to below 140°C, the regulator operation resumes.

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
TPS76301QDBVRG4Q1	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS76301QDBVRQ1	ACTIVE	SOT-23	DBV	5	3000	TBD	CU NIPDAU	Level-1-220C-UNLIM
TPS76316QDBVRG4Q1	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS76316QDBVRQ1	ACTIVE	SOT-23	DBV	5	3000	TBD	CU NIPDAU	Level-1-220C-UNLIM
TPS76318QDBVRG4Q1	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS76318QDBVRQ1	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS76325QDBVRG4Q1	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS76325QDBVRQ1	ACTIVE	SOT-23	DBV	5	3000	TBD	CU NIPDAU	Level-1-220C-UNLIM
TPS76330QDBVRG4Q1	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS76330QDBVRQ1	ACTIVE	SOT-23	DBV	5	3000	TBD	CU NIPDAU	Level-1-220C-UNLIM
TPS76333QDBVRG4Q1	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS76333QDBVRQ1	ACTIVE	SOT-23	DBV	5	3000	TBD	CU NIPDAU	Level-1-220C-UNLIM
TPS76350QDBVRG4Q1	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS76350QDBVRQ1	ACTIVE	SOT-23	DBV	5	3000	TBD	CU NIPDAU	Level-1-220C-UNLIM

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

Important Information and Disclaimer:The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF TPS76301-Q1, TPS76316-Q1, TPS76318-Q1, TPS76325-Q1, TPS76330-Q1, TPS76333-Q1, TPS76350-Q1

:

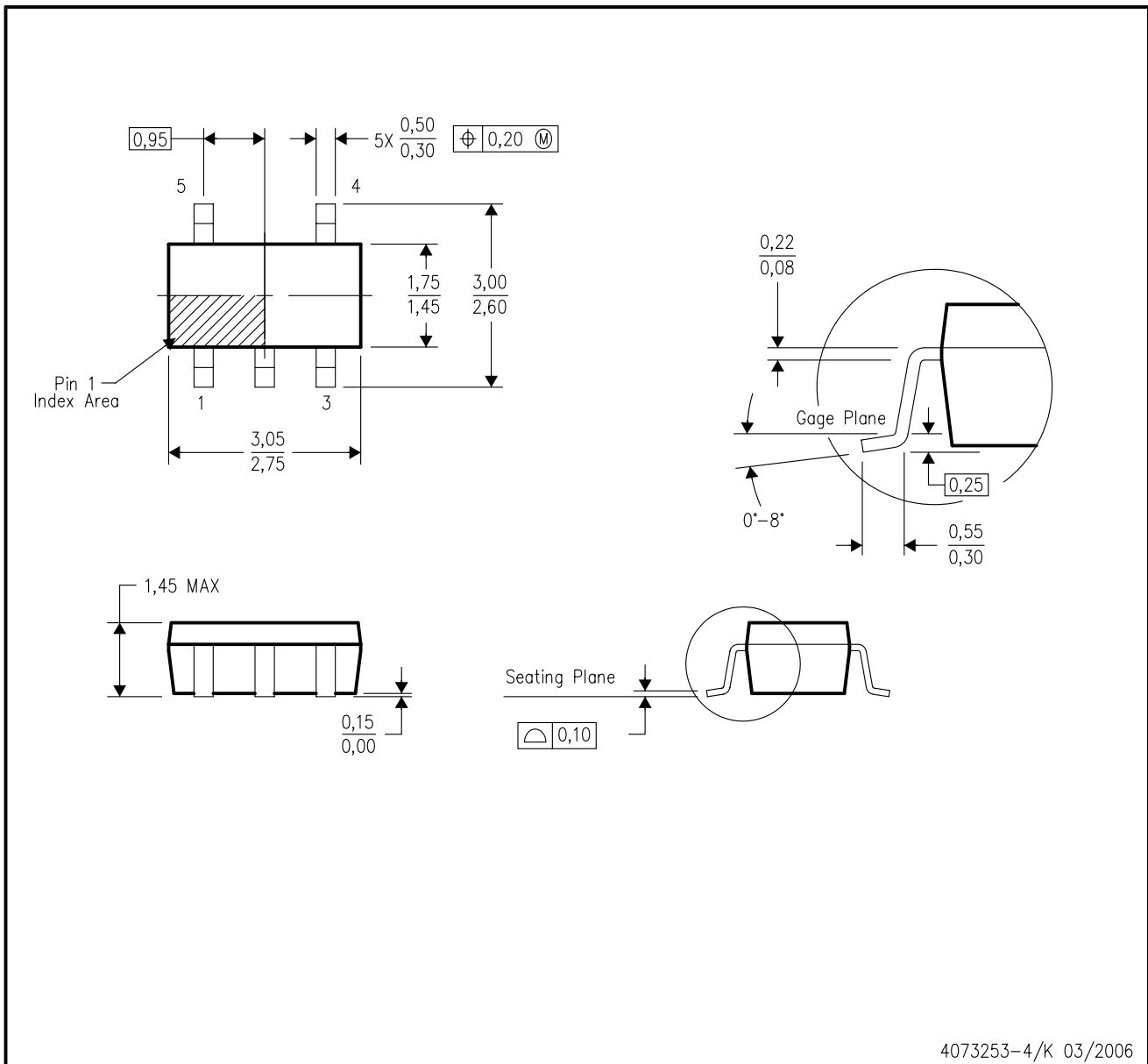
- Catalog: [TPS76301](#), [TPS76316](#), [TPS76318](#), [TPS76325](#), [TPS76330](#), [TPS76333](#), [TPS76350](#)

NOTE: Qualified Version Definitions:

- Catalog - TI's standard catalog product

DBV (R-PDSO-G5)

PLASTIC SMALL-OUTLINE PACKAGE



4073253-4/K 03/2006

- NOTES:
- All linear dimensions are in millimeters.
 - This drawing is subject to change without notice.
 - Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
 - Falls within JEDEC MO-178 Variation AA.

IMPORTANT NOTICE

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, modifications, enhancements, improvements, and other changes to its products and services at any time and to discontinue any product or service without notice. Customers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All products are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its hardware products to the specifications applicable at the time of sale in accordance with TI's standard warranty. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by government requirements, testing of all parameters of each product is not necessarily performed.

TI assumes no liability for applications assistance or customer product design. Customers are responsible for their products and applications using TI components. To minimize the risks associated with customer products and applications, customers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any TI patent right, copyright, mask work right, or other TI intellectual property right relating to any combination, machine, or process in which TI products or services are used. Information published by TI regarding third-party products or services does not constitute a license from TI to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of TI information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. Reproduction of this information with alteration is an unfair and deceptive business practice. TI is not responsible or liable for such altered documentation. Information of third parties may be subject to additional restrictions.

Resale of TI products or services with statements different from or beyond the parameters stated by TI for that product or service voids all express and any implied warranties for the associated TI product or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

TI products are not authorized for use in safety-critical applications (such as life support) where a failure of the TI product would reasonably be expected to cause severe personal injury or death, unless officers of the parties have executed an agreement specifically governing such use. Buyers represent that they have all necessary expertise in the safety and regulatory ramifications of their applications, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of TI products in such safety-critical applications, notwithstanding any applications-related information or support that may be provided by TI. Further, Buyers must fully indemnify TI and its representatives against any damages arising out of the use of TI products in such safety-critical applications.

TI products are neither designed nor intended for use in military/aerospace applications or environments unless the TI products are specifically designated by TI as military-grade or "enhanced plastic." Only products designated by TI as military-grade meet military specifications. Buyers acknowledge and agree that any such use of TI products which TI has not designated as military-grade is solely at the Buyer's risk, and that they are solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI products are neither designed nor intended for use in automotive applications or environments unless the specific TI products are designated by TI as compliant with ISO/TS 16949 requirements. Buyers acknowledge and agree that, if they use any non-designated products in automotive applications, TI will not be responsible for any failure to meet such requirements.

Following are URLs where you can obtain information on other Texas Instruments products and application solutions:

Products

Amplifiers	amplifier.ti.com
Data Converters	dataconverter.ti.com
DSP	dsp.ti.com
Clocks and Timers	www.ti.com/clocks
Interface	interface.ti.com
Logic	logic.ti.com
Power Mgmt	power.ti.com
Microcontrollers	microcontroller.ti.com
RFID	www.ti-rfid.com
RF/IF and ZigBee® Solutions	www.ti.com/lprf

Applications

Audio	www.ti.com/audio
Automotive	www.ti.com/automotive
Broadband	www.ti.com/broadband
Digital Control	www.ti.com/digitalcontrol
Medical	www.ti.com/medical
Military	www.ti.com/military
Optical Networking	www.ti.com/opticalnetwork
Security	www.ti.com/security
Telephony	www.ti.com/telephony
Video & Imaging	www.ti.com/video
Wireless	www.ti.com/wireless

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265
Copyright © 2008, Texas Instruments Incorporated